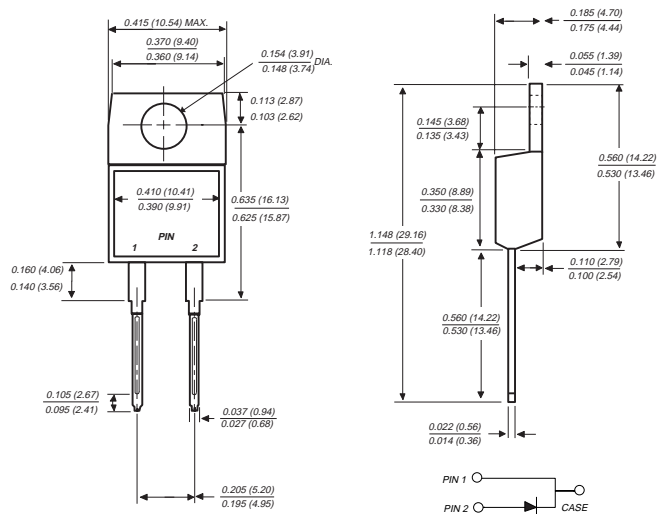


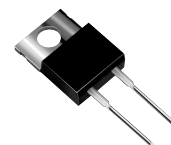
MBR735 THRU MBR760

TO-220AC



FEATURES

- ◆ Plastic package has Underwriters Laboratory Flammability Classifications 94V-0
- ◆ Metal to silicon rectifier, majority carrier conduction
- ◆ Low power loss, high efficiency
- ◆ High current capability, low forward voltage drop
- ◆ High surge capability
- ◆ For use in low voltage, high frequency inverters, free wheeling, and polarity protection applications
- ◆ Guardring for overvoltage protection
- ◆ High temperature soldering guaranteed: 250°C/10 seconds, 0.25" (6.35mm) from case



MECHANICAL DATA

Case: JEDEC TO-220AC molded plastic body
Terminals: Lead solderable per MIL-STD-750, Method 2026
Polarity: As marked
Mounting Position: Any
Mounting Torque: 5 in. - lbs. max.
Weight: 0.08 ounces, 2.24 grams

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25°C ambient temperature unless otherwise specified.

	SYMBOLS	MBR735	MBR745	MBR750	MBR760	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	35	45	50	60	Volts
Maximum working peak reverse voltage	V_{RWM}	35	45	50	60	Volts
Maximum DC blocking voltage	V_{DC}	35	45	50	60	Volts
Maximum average forward rectified current (SEE FIG 1)	$I_{(AV)}$	7.5				Amps
Peak repetitive forward current (square wave, 20 KHz) at $T_C=105^\circ\text{C}$	I_{FRM}	15.0				Amps
Peak forward surge current, 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150.0				Amps
Peak repetitive reverse surge current (NOTE 1)	I_{RRM}	1.0		0.5		Amps
Maximum instantaneous forward voltage at (NOTE 2)	V_F	$I_F=7.5\text{A}, T_C=25^\circ\text{C}$ $I_F=7.5\text{A}, T_C=125^\circ\text{C}$ $I_F=15\text{A}, T_C=25^\circ\text{C}$ $I_F=15\text{A}, T_C=125^\circ\text{C}$		0.75 0.65 - -		Volts
Maximum instantaneous reverse current at rated DC blocking voltage (NOTE 1)	I_R	$T_C=25^\circ\text{C}$ $T_C=125^\circ\text{C}$		0.5 50		mA
Voltage rate of change (rated V_R)	dv/dt	10,000				V/ μs
Maximum thermal resistance, (NOTE 3)	$R_{\theta JC}$ $R_{\theta JA}$	3.0 60.0				$^\circ\text{C}/\text{W}$
Operating junction temperature range	T_J	-65 to +150				$^\circ\text{C}$
Storage temperature range	T_{STG}	-65 to +175				$^\circ\text{C}$

NOTES:

- (1) 2.0 μs , pulse width, $f=1.0\text{ KHz}$
- (2) Pulse test: 300 μs pulse width, 1% duty cycle
- (3) Thermal resistance from junction to case and/or thermal resistance from junction to ambient

RATINGS AND CHARACTERISTIC CURVES MBR735 THRU MBR760

FIG. 1 - FORWARD CURRENT DERATING CURVE

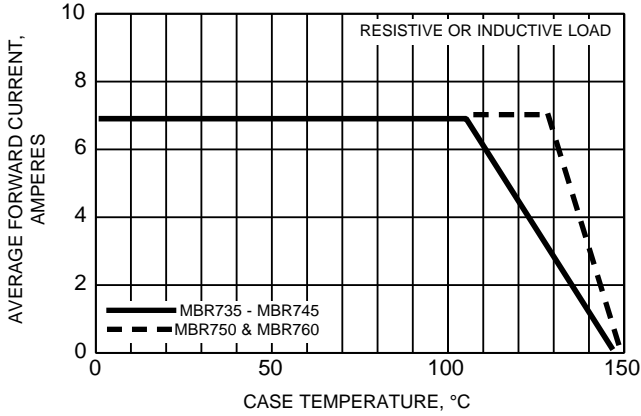


FIG. 2 - MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

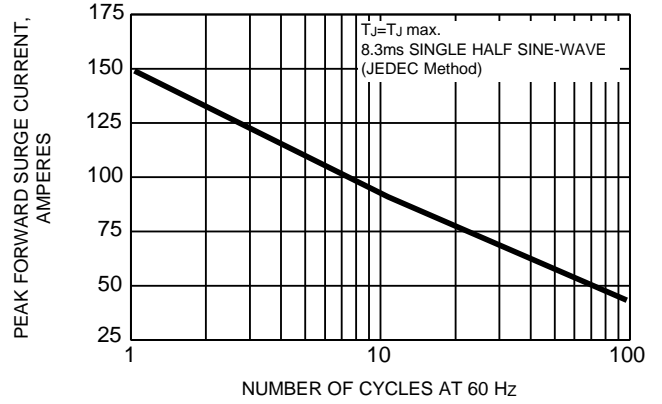


FIG. 3 - TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

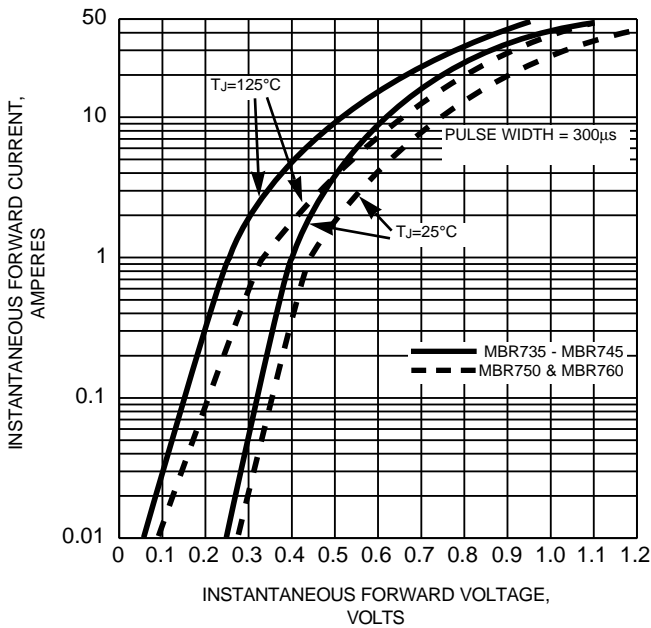


FIG. 4 - TYPICAL REVERSE CHARACTERISTICS

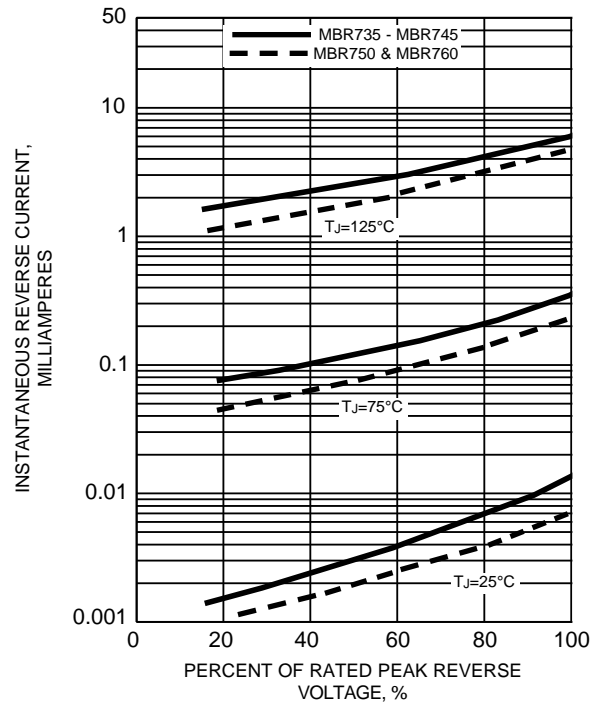


FIG. 5 - TYPICAL JUNCTION CAPACITANCE

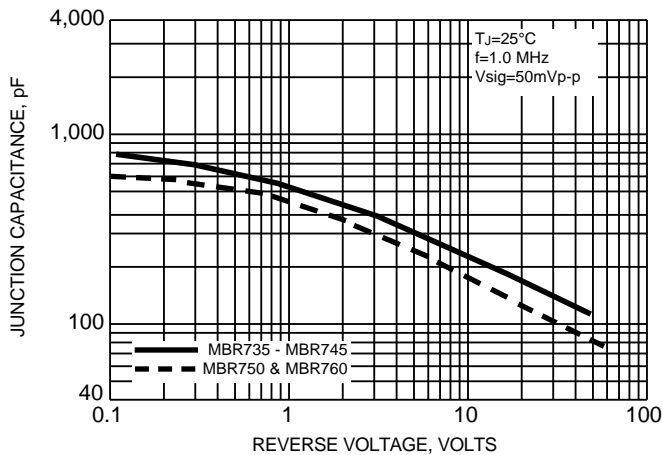


FIG. 6 - TYPICAL TRANSIENT THERMAL IMPEDANCE

